## TOSHIBA HALL SENSOR GaAs ION IMPLANTED PLANAR TYPE

## THS126

HIGH STABILITY MOTOR CONTROL.

DIGITAL TACHOMETER.

CRANK SHAFT POSITION SENSOR.

Excellent Temperature Characteristics.

Wide Operating Temperature Range. (; −55~125°C)

Excellent Output Voltage Linearity.

High Internal Resistance. :  $R_d = 1000\Omega$  (Min.)

Low Residual Voltage Ratio. :  $V_{HO}/V_{H} = \pm 5\%$  (Max.)

## MAXIMUM RATINGS (Ta = 25°C)

SYMBOL	RATING	UNIT
$v_{\mathbf{C}}$	12	V
$P_{\mathbf{D}}$	150	mW
${ m T_{opr}}$	-55~125	°C
$\mathrm{T_{stg}}$	-55~150	$^{\circ}\mathrm{C}$
	V <sub>C</sub> P <sub>D</sub> T <sub>opr</sub>	V <sub>C</sub> 12 P <sub>D</sub> 150 T <sub>opr</sub> -55~125

0.6 MAX 1(+) - 3(-) (INPUT) 2(+)-4(-)(OUTPUT)**JEDEC EIAJ** TOSHIBA 10-4B1A

Unit in mm

Weight: 0.06g

## ELECTRICAL CHARACTERISTICS (Ta = 25°C)

CHARACTERISTIC		SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Internal Resistance (Input)		$R_d$	$I_C = 1mA$	1000	1250	1500	Ω
Residual Voltage Ratio		$v_{\mathrm{HO}}/v_{\mathrm{H}}$	$V_C = 5V, B = 0/B = 0.1T$	_	_	±5	%
Hall Voltage	(Note 1)	$v_{ m H}$	$V_C = 5V, B = 0.1T$	130	150	170	mV
Temperature Coefficient (Note 2)		$ m V_{HT}$	I <sub>C</sub> =5mA, B=0.1T T1=25°C, T2=125°C	_	_	-0.06	%/°C
Linearity	(Note 3)	$_{\it \Delta K_{ m H}}$	$V_C = 5V$ , $B1 = 0.05T$ , $B2 = 0.1T$	_	_	2	%
Specific Sensitivity	(Note 4)	K*	$V_C = 5V, B = 0.1T$	_	30	_	$\times 10^{-2} / \mathrm{T}$
Internal Resistance	(Output)	$R_{ m OUT}$	$I_C = 1mA$	1800	2375	3000	Ω

Note 1 :  $V_H = V_{HM} - V_{HO} (V_{HM})$  is meter indication)

Note 2: 
$$V_{HT} = \frac{1}{V_{H/(T1)}} \cdot \frac{V_{H/(T2)} - V_{H/(T1)}}{T_{2} - T_{1}} \times 100 \, (\% \, ^{\circ}\text{C})$$
  $V_{HO}$ : Residual Voltage

Note 2 : 
$$V_{HT} = \frac{1}{V_{H \, (T1)}} \cdot \frac{V_{H \, (T2)} - V_{H \, (T1)}}{T2 - T1} \times 100 \, (\%/^{\circ}C)$$
  $V_{HO}$  : Residual Voltage Note 3 :  $\Delta K_{H} = \frac{K_{H \, (B2)} - K_{H \, (B1)}}{1/2 \{ K_{H \, (B1)} + K_{H \, (B2)} \}} \times 100 \, (\%)$ ,  $K_{H} = \frac{V_{H}}{I_{C} \cdot B}$   $K_{H}$  : Product Sensitivity

Note 4:  $K^*=V_H/(R_d\times I_C\times B)=K_H/R_d$ 

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